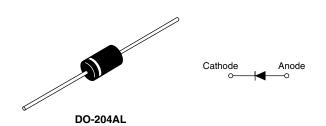


Vishay High Power Products

Schottky Rectifier, 1.1 A



PRODUCT SUMMARY				
I _{F(AV)}	1.1 A			
V_{R}	30/40 V			

FEATURES

- Low profile, axial leaded outline
- High frequency operation



- Very low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability
- · Lead (Pb)-free plating
- Designed and qualified for industrial level

DESCRIPTION

The 11DQ.. axial leaded Schottky rectifier has been optimized for very low forward voltage drop, with moderate leakage. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS					
SYMBOL	CHARACTERISTICS	VALUES	UNITS		
I _{F(AV)}	Rectangular waveform	1.1	A		
V _{RRM}		30/40	V		
I _{FSM}	$t_p = 5 \mu s sine$	225	A		
V _F	1 Apk, T _J = 25 °C	0.55	V		
T _J	Range	- 40 to 150	°C		

VOLTAGE RATINGS					
PARAMETER	SYMBOL	11DQ03	11DQ04	UNITS	
Maximum DC reverse voltage	V_{R}	30	40	V	
Maximum working peak reverse voltage	V_{RWM}	30	40	V	

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average forward current See fig. 4	I _{F(AV)}	I _{F(AV)} 50 % duty cycle at T _C = 75 °C, rectangular waveform		1.1	
Maximum peak one cycle non-repetitive surge current	l=a	5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated V _{RRM} applied	225	Α
See fig. 6	IFSM	10 ms sine or 6 ms rect. pulse		35	
Non-repetitive avalanche energy	E _{AS}	$T_J = 25 ^{\circ}\text{C}, I_{AS} = 1.0 \text{A}, L = 6 \text{mH}$		3.0	mJ
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T_J maximum $V_A = 1.5$ x V_R typical		1.0	Α

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11DQ03, 11DQ04

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ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum forward voltage drop	V _{FM} ⁽¹⁾	1 A	T _J = 25 °C	0.55	V
		2 A		0.71	
See fig. 1	V FM (*)	1 A	T _J = 125 °C	0.50	
		2 A		0.61	
Maximum reverse leakage current	ximum reverse leakage current	T _J = 25 °C	V _R = Rated V _R	1.0	mA
See fig. 2	'RM \''	T _J = 125 °C		6.0	
Typical junction capacitance	C _T	$V_R = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz) 25 °C		60	pF
Typical series inductance	L _S	Measured lead to lead 5 mm from package body		8.0	nΗ
Maximum voltage rate of change	dV/dt	Rated V _R		10 000	V/µs

Note

 $^{^{(1)}\,}$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range	T _J ⁽¹⁾ , T _{Stg}		- 40 to 150	°C
Maximum thermal resistance, junction to ambient	R _{thJA}	DC operation Without cooling fin	100	°C/W
Typical thermal resistance, junction to lead	R _{thJL}	DC operation See fig. 4	81	G/VV
Approximate weight			0.33	g
Approximate weight			0.012	OZ.
Marking device		Case style DO-204AL (DO-41)	11DQ03	
			11D	Q04

Note

$$^{(1)} \quad \frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}} \quad \text{thermal runaway condition for a diode on its own heatsink}$$



Schottky Rectifier, 1.1 A Vishay High Power Products

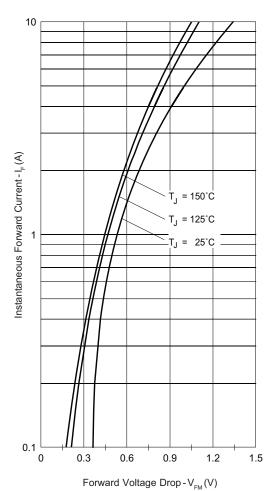


Fig. 1 - Maximum Forward Voltage Drop Characteristics

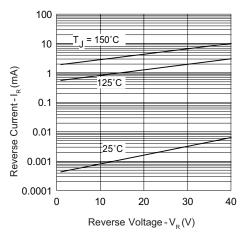


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

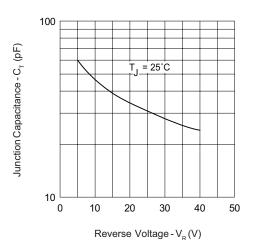


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

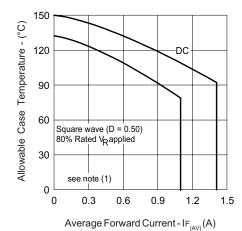


Fig. 4 - Maximum Allowable Case Temperature vs.
Average Forward Current

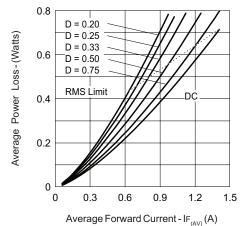


Fig. 5 - Forward Power Loss Characteristics

Note

(1) Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$; $Pd = Forward power loss = I_{F(AV)} \times V_{FM}$ at $(I_{F(AV)}/D)$ (see fig. 6); $Pd_{REV} = Inverse power loss = V_{R1} \times I_R$ (1 - D); I_R at $V_{R1} = 80$ % rated V_R

Vishay High Power Products Schottky Rectifier, 1.1 A



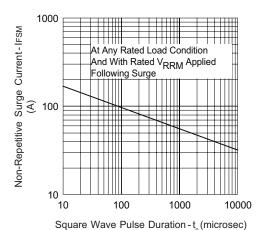
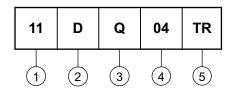


Fig. 6 - Maximum Non-Repetitive Surge Current

ORDERING INFORMATION TABLE

Device code



1 - 11 = 1.1 A (axial and small packages - current is x 10)

2 - D = DO-41 package

3 - Q = Schottky Q., series

TR = Tape and reel package (5000 pcs)

None = Box package (1000 pcs)

LINKS TO RELATED DOCUMENTS			
Dimensions http://www.vishay.com/doc?95241			
Part marking information http://www.vishay.com/doc?95304			
Packaging information	http://www.vishay.com/doc?95308		

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